

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PATENT APPLICATION

Inventor(s):

Sang-Wook Cheong

Namjung Hur

Case:

5-1

Serial No.:

09/885471 June 20, 2001

Filing Date: Examiner:

E. Fuller

Group Art Unit:

1762

Title:

MgB₂ Superconductors

COMMISSIONER FOR PATENTS P.O. BOX 1450 **ALEXANDRIA, VA 22313-1450**

SIR:

CERTIFICATE OF CORRECTION

Enclosed is a request for a Certificate of Correction for U.S. Patent No. 6.878,420 issued on April 12, 2005 requesting a correction to the title of the patent.

In the issued patent, the title is "MGB2 SUPERCONDUCTORS" rather than "MgB2 SUPERCONDUCTORS" as shown at page 1 of the filed application (enclosed). The symbol "MG" is incorrect, because "Mg" and not "MG" is the recognized scientific abbreviation for the element "magnesium". Since page 1 of the filed application shows the title correctly, it appears that the U.S. Patent and trademark Office made a printing error. Also enclosed is a copy of the first page of the above patent application.

This is a USPTO error and therefore **no fee** should be due for the filing of this Certificate of Correction.

In the event of any non-payment or improper payment of a required fee, the Commissioner is authorized to charge or to credit Lucent Technologies Deposit Account No. 12-2325 as required to correct the error.

Respectfully,

John F. McCabe, Attorney

Rea. No. 42854

908-582-6866

Docket Administrator (Room 3J-219)

Lucent Technologies Inc. 101 Crawfords Corner Road Holmdel, NJ 07733-3030

Date of Deposit I hereby certify that this correspondence is being deposited with the United States Postal Service in a First Class Mail envelope on the date indicated above and is addressed to: Mail Stop

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	CERTIFICATE OF CORRECTION
	Page 1 of 1
PATENT NO. :	6,878,420
APPLICATION NO.:	09/885,471
ISSUE DATE :	April 12, 2005
INVENTOR(S) :	Sang-Wook Cheong and Namjung Hur
	d that an error appears or errors appear in the above-identified patent and that said Letters Patent ted as shown below:
	At page 1, column 1,
	the title on the above patent applicaton should be changed from:
	"MGB ₂ SUPERCONDUCTORS" to
	MGB ₂ , SUPERCONDUCTORS

MAILING ADDRESS OF SENDER (Please do not use customer number below): Lucent Technologies

Docket Administrator, Rm. 3J-219 101 Crawfords Corner Road Holmdel, NJ 07733-3030

This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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(MgB₂|SUPERCONDUCTORS

This application claims the benefit of U.S. Provisional Application No. 60/275,067, filed on March 12, 2001.

BACKGROUND

Field of the Invention

This invention relates to superconductors and devices based on superconductors.

5 Discussion of the Related Art

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Recently, Akitmitsu et al. discovered that a well-known compound, i.e., MgB₂, exhibits superconductivity at temperatures lower than about 39 Kelvin (K). Powders formed of MgB₂ are produced by chemically reacting magnesium (Mg) and boron (B) at a temperature in the range of about 800° Celsius to about 950° Celsius (C). Powders of polycrystalline MgB₂ in which individual crystalline grains of MgB₂ have diameters in the range of about 1 micron to about 50 microns are available commercially.

SUMMARY

In one aspect, the invention features a solid structure. The structure includes a substrate and a layer located on a surface of the substrate. The layer includes crystalline or polycrystalline MgB₂.

In another aspect, the invention features a process for making a thin-layer device. The process includes providing a solid body of MgB₂ and ejecting MgB₂ from the body by directing laser light onto the body. The process also includes growing a layer on a surface of a substrate from a portion of the ejected MgB₂.

BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 is a magnified view of a portion of a solid polycrystalline body formed of MgB₂;

Figure 2 is a flow chart for a process of producing the body of Figure 1; Figure 3 shows a structure that includes a thin layer of MgB₂;

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